

BIPOLAR ANALOG INTEGRATED CIRCUIT μ PC8179TK

SILICON MMIC LOW CURRENT AMPLIFIER FOR MOBILE COMMUNICATIONS

DESCRIPTION

The μ PC8179TK is a silicon monolithic integrated circuit designed as amplifier for mobile communications. This IC can realize low current consumption with external chip inductor which can not be realized on internal 50 Ω wide band matched IC. μ PC8179TK adopts 6-pin lead-less minimold package using same chip as the conventional μ PC8179TB in 6-pin super minimold.

TK suffix IC which is smaller package than TB suffix IC contributes to reduce mounting space by 50%.

This IC is manufactured using our 30 GHz f_{\max} UHS0 (Ultra High Speed Process) silicon bipolar process.

FEATURES

- Low current consumption : $I_{CC} = 4.0$ mA TYP. @ $V_{CC} = 3.0$ V
- Supply voltage : $V_{CC} = 2.4$ to 3.3 V
- Excellent isolation : ISL = 43.0 dB TYP. @ $f = 1.0$ GHz
ISL = 42.0 dB TYP. @ $f = 1.9$ GHz
ISL = 42.0 dB TYP. @ $f = 2.4$ GHz
- Power gain : $G_P = 13.5$ dB TYP. @ $f = 1.0$ GHz
 $G_P = 15.5$ dB TYP. @ $f = 1.9$ GHz
 $G_P = 16.0$ dB TYP. @ $f = 2.4$ GHz
- Gain 1 dB compression output power : $P_{O(1\text{ dB})} = +2.0$ dBm TYP. @ $f = 1.0$ GHz
 $P_{O(1\text{ dB})} = +0.5$ dBm TYP. @ $f = 1.9$ GHz
 $P_{O(1\text{ dB})} = +0.5$ dBm TYP. @ $f = 2.4$ GHz
- Operating frequency : 0.1 to 2.4 GHz (Output port LC matching)
- High-density surface mounting : 6-pin lead-less minimold package (1.5 \times 1.3 \times 0.55 mm)
- Light weight : 3 mg (Standard value)

APPLICATION

- Buffer amplifiers on 0.1 to 2.4 GHz mobile communications system

Caution electro-static sensitive devices.

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Not all devices/types available in every country. Please check with local NEC Compound Semiconductor Devices representative for availability and additional information.

ORDERING INFORMATION

Part Number	Package	Marking	Supplying Form
μ PC8179TK-E2	6-pin lead-less minimold (1511)	6C	<ul style="list-style-type: none"> Embossed tape 8 mm wide Pin 4,5,6 are in pull-out direction. Qty 5 kpcs/reel

Remark To order evaluation samples, contact your nearby sales office.

Part number for sample order: μ PC8179TK

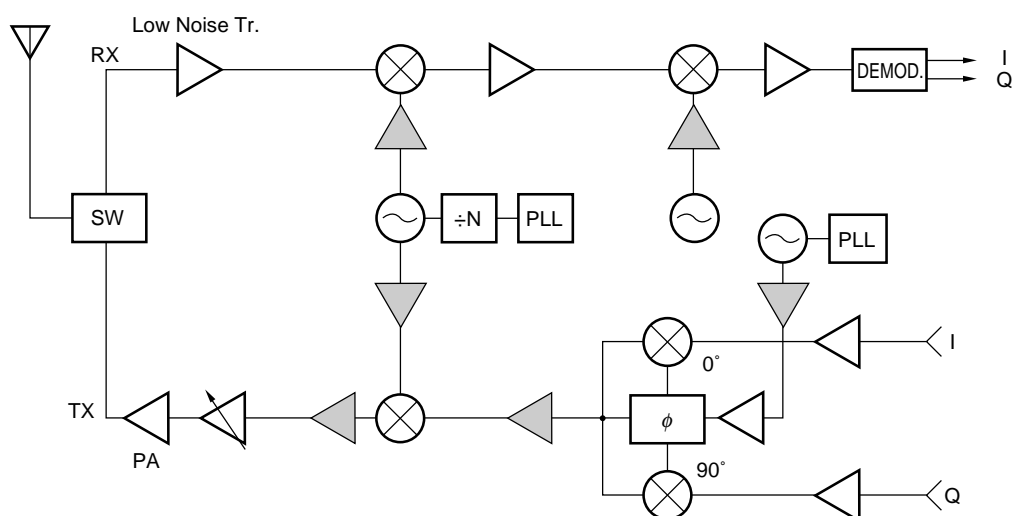
PRODUCT LINE-UP ($T_A = +25^\circ\text{C}$, $V_{CC} = V_{out} = 3.0\text{ V}$, $Z_S = Z_L = 50\ \Omega$)

Parameter Part No.	I_{CC} (mA)	1.0 GHz output port matching frequency			1.66 GHz output port matching frequency			1.9 GHz output port matching frequency			2.4 GHz output port matching frequency			Marking
		G_P (dB)	ISL (dB)	$P_{O(1dB)}$ (dBm)	G_P (dB)	ISL (dB)	$P_{O(1dB)}$ (dBm)	G_P (dB)	ISL (dB)	$P_{O(1dB)}$ (dBm)	G_P (dB)	ISL (dB)	$P_{O(1dB)}$ (dBm)	
μ PC8178TB	1.9	11.0	39.0	-4.0	-	-	-	11.5	40.0	-7.0	11.5	38.0	-7.5	C3B
μ PC8178TK	1.9	11.0	40.0	-5.5	-	-	-	11.0	41.0	-8.0	11.0	42.0	-8.0	6B
μ PC8179TB	4.0	13.5	44.0	+3.0	-	-	-	15.5	42.0	+1.5	15.5	41.0	+1.0	C3C
μ PC8179TK	4.0	13.5	43.0	+2.0	-	-	-	15.5	42.0	+0.5	16.0	42.0	+0.5	6C
μ PC8128TB	2.8	12.5	39.0	-4.0	13.0	39.0	-4.0	13.0	37.0	-4.0	-	-	-	C2P
μ PC8151TB	4.2	12.5	38.0	+2.5	15.0	36.0	+1.5	15.0	34.0	+0.5	-	-	-	C2U
μ PC8152TB	5.6	23.0	40.0	-4.5	19.5	38.0	-8.5	17.5	35.0	-8.5	-	-	-	C2V

Remark Typical performance. Please refer to ELECTRICAL CHARACTERISTICS in detail.

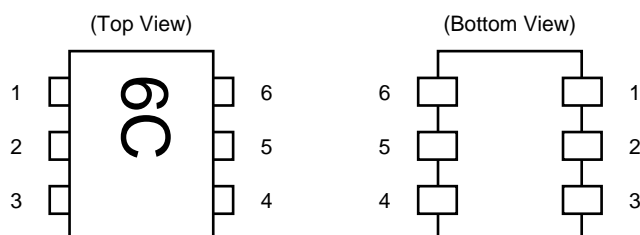
SYSTEM APPLICATION EXAMPLE

Location examples in digital cellular



These ICs can be added to your system around Δ parts, when you need more isolation or gain. The application herein, however, shows only examples, therefore the application can depend on your kit evaluation.

PIN CONNECTIONS



Pin No.	Pin Name
1	INPUT
2	GND
3	GND
4	OUTPUT
5	GND
6	V _{CC}

PIN EXPLANATION

Pin No.	Pin Name	Applied Voltage (V)	Pin Voltage (V) ^{Note}	Function and Applications	Internal Equivalent Circuit
1	INPUT	–	0.90	Signal input pin. A internal matching circuit, configured with resistors, enables 50 Ω connection over a wide band. This pin must be coupled to signal source with capacitor for DC cut.	
2 3 5	GND	0	–	Ground pin. This pin should be connected to system ground with minimum inductance. Ground pattern on the board should be formed as wide as possible. All the ground pins must be connected together with wide ground pattern to decrease impedance defference.	
4	OUTPUT	Voltage as same as V _{CC} through external inductor	–	Signal output pin. This pin is designed as collector output. Due to the high impedance output, this pin should be externally equipped with LC matching circuit to next stage. For L, a size 1 005 chip inductor can be chosen.	
6	V _{CC}	2.4 to 3.3	–	Power supply pin. This pin should be externally equipped with bypass capacitor to minimize its impedance.	

Note Pin voltage is measured at V_{CC} = 3.0 V.

ABSOLUTE MAXIMUM RATINGS

Parameter	Symbol	Test Conditions	Ratings	Unit
Supply Voltage	V _{CC}	T _A = +25°C, Pin 4, Pin 6	3.6	V
Circuit Current	I _{CC}	T _A = +25°C	15	mA
Power Dissipation	P _D	T _A = +85°C Note	232	mW
Operating Ambient Temperature	T _A		−40 to +85	°C
Storage Temperature	T _{stg}		−55 to +150	°C
Input Power	P _{in}	T _A = +25°C	+5	dBm

Note Mounted on double-sided copper-clad 50 × 50 × 1.6 mm epoxy glass PWB

RECOMMENDED OPERATING RANGE

Parameter	Symbol	MIN.	TYP.	MAX.	Unit	Remarks
Supply Voltage	V _{CC}	2.4	3.0	3.3	V	The same voltage should be applied to pin 4 and pin 6.
Operating Ambient Temperature	T _A	−40	+25	+85	°C	

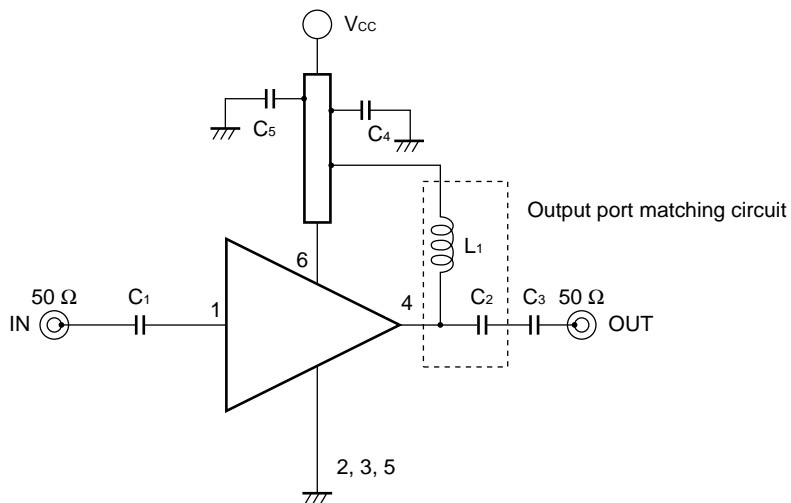
ELECTRICAL CHARACTERISTICS

(Unless otherwise specified, T_A = +25°C, V_{CC} = V_{out} = 3.0 V, Z_s = Z_L = 50 Ω, at LC matched frequency)

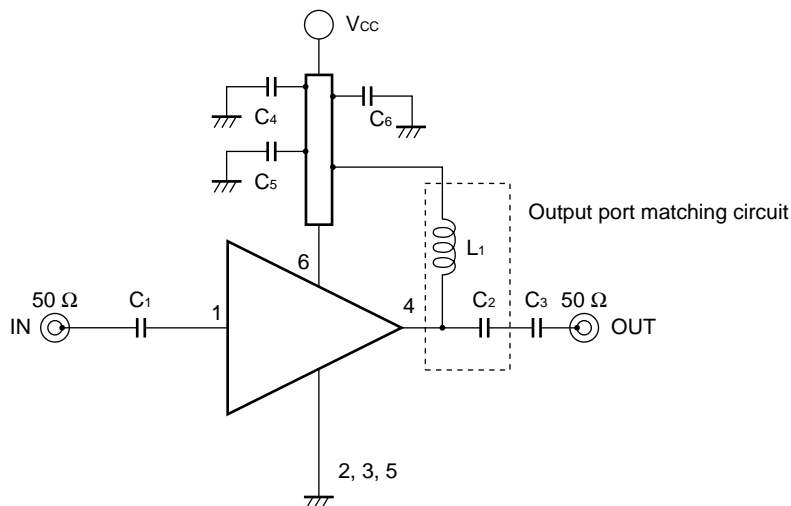
Parameter	Symbol	Test Conditions	MIN.	TYP.	MAX.	Unit
Circuit Current	I _{CC}	No signal	2.9	4.0	5.4	mA
Power Gain	G _P	f = 1.0 GHz, P _{in} = −30 dBm	11.0	13.5	15.5	dB
		f = 1.9 GHz, P _{in} = −30 dBm	13.0	15.5	17.5	
		f = 2.4 GHz, P _{in} = −30 dBm	14.0	16.0	18.5	
Isolation	ISL	f = 1.0 GHz, Pin = −30 dBm	39.0	43.0	−	dB
		f = 1.9 GHz, Pin = −30 dBm	37.0	42.0	−	
		f = 2.4 GHz, Pin = −30 dBm	37.0	42.0	−	
Gain 1 dB Compression Output Power	P _{O(1 dB)}	f = 1.0 GHz	−0.5	+2.0	−	dBm
		f = 1.9 GHz	−2.0	+0.5	−	
		f = 2.4 GHz	−3.0	+0.5	−	
Noise Figure	NF	f = 1.0 GHz	−	5.0	6.5	dB
		f = 1.9 GHz	−	5.0	6.5	
		f = 2.4 GHz	−	5.0	6.5	
Input Return Loss	RL _{in}	f = 1.0 GHz, Pin = −30 dBm	4.0	7.0	−	dB
		f = 1.9 GHz, Pin = −30 dBm	4.0	7.0	−	
		f = 2.4 GHz, Pin = −30 dBm	6.0	9.0	−	

TEST CIRCUITS

<1> $f = 1.0 \text{ GHz}$



<2> $f = 1.9 \text{ GHz}$



<3> $f = 2.4 \text{ GHz}$

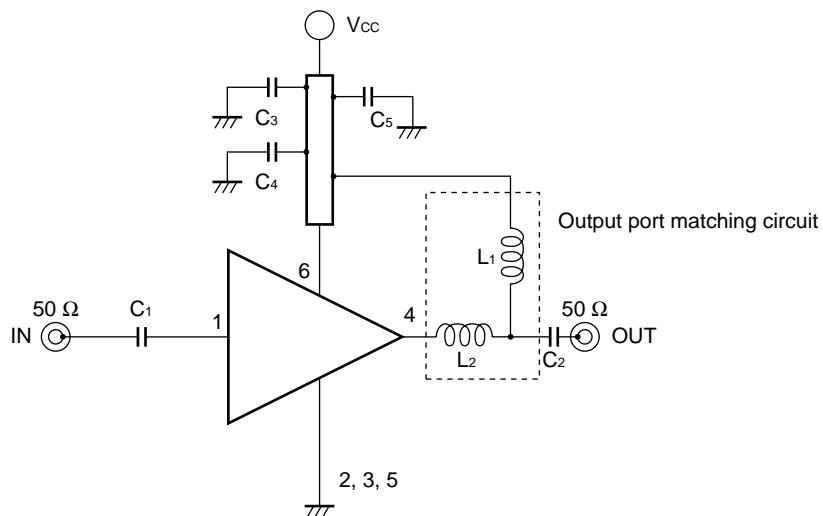
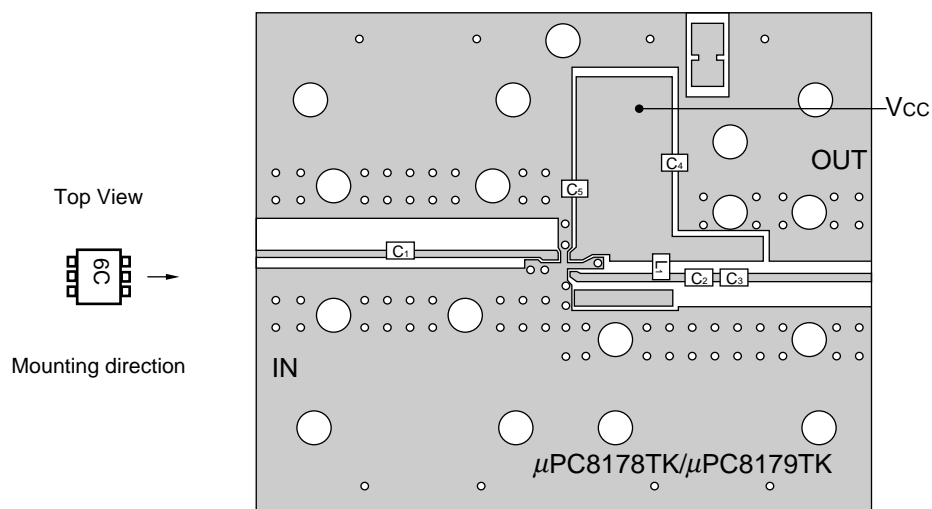


ILLUSTRATION OF THE TEST CIRCUIT ASSEMBLED ON EVALUATION BOARD

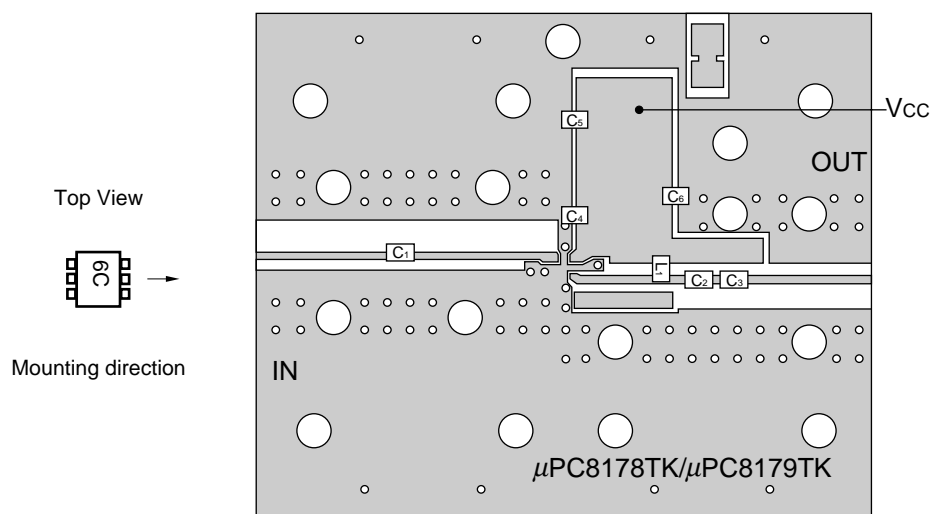
<1> $f = 1.0 \text{ GHz}$



COMPONENT LIST

	1.0 GHz Output Port Matching
C ₁ , C ₃	1 000 pF
C ₂	0.75 pF
C ₄	5 pF
C ₅	8 pF
L ₁	12 nH

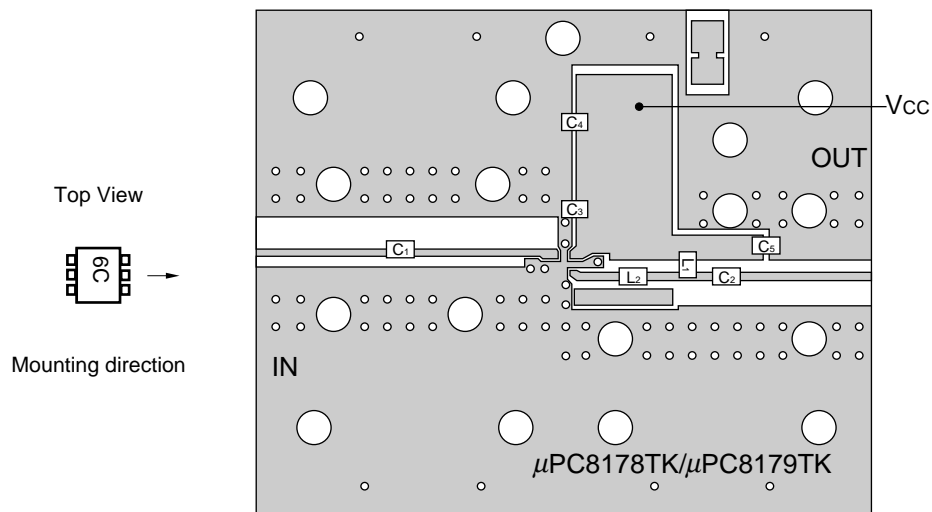
<2> $f = 1.9 \text{ GHz}$



COMPONENT LIST

	1.9 GHz Output Port Matching
C1, C3, C5, C6	1 000 pF
C2	0.5 pF
C4	8 pF
L1	2.7 nH

<3> $f = 2.4 \text{ GHz}$



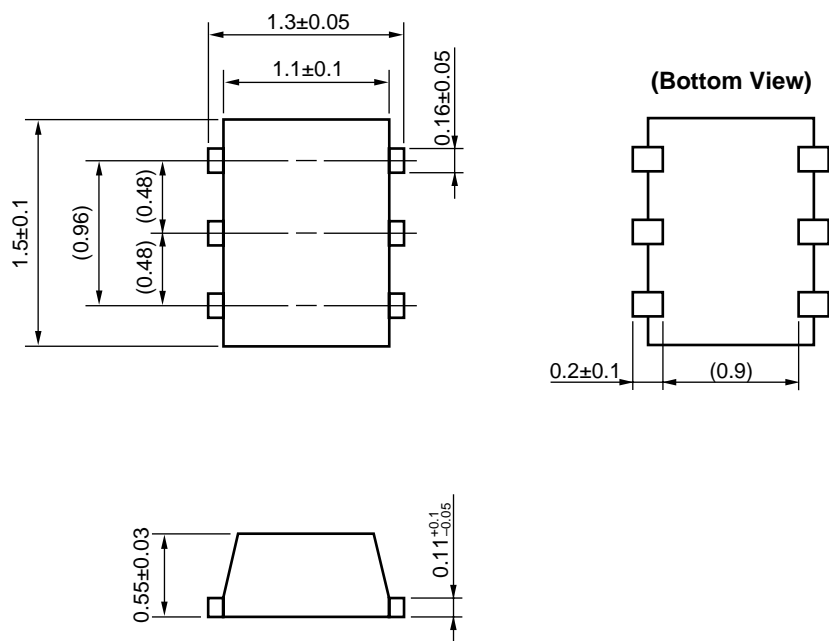
COMPONENT LIST

	2.4 GHz Output Port Matching
C ₁ , C ₂ , C ₄ , C ₅	1 000 pF
C ₃	10 pF
L ₁	1.8 nH
L ₂	2.7 nH

- Remarks**
1. 42 × 35 × 0.4 mm double-sided copper-clad polyimide board
 2. Back side: GND pattern
 3. Gold plated on pattern
 4. oO:Through holes

PACKAGE DIMENSIONS

6-PIN LEAD-LESS MINIMOLD (1511) (UNIT: mm)



Remark (): reference

NOTE ON CORRECT USE

- (1) Observe precautions for handling because of electro-static sensitive devices.
- (2) Form a ground pattern as widely as possible to minimize ground impedance (to prevent undesired oscillation).
All the ground pins must be connected together with wide ground pattern to decrease impedance difference.
- (3) The bypass capacitor should be attached to Vcc line.
- (4) The inductor (L) should be attached between output and Vcc pins. The L and series capacitor (C) values should be adjusted for applied frequency to match impedance to next stage.
- (5) The DC capacitor must be attached to input pin.

RECOMMENDED SOLDERING CONDITIONS

This product should be soldered and mounted under the following recommended conditions. For soldering methods and conditions other than those recommended below, contact your nearby sales office.

Soldering Method	Soldering Conditions	Condition Symbol
Infrared Reflow	Peak temperature (package surface temperature) : 260°C or below Time at peak temperature : 10 seconds or less Time at temperature of 220°C or higher : 60 seconds or less Preheating time at 120 to 180°C : 120±30 seconds Maximum number of reflow processes : 3 times Maximum chlorine content of rosin flux (% mass) : 0.2%(Wt.) or below	IR260
VPS	Peak temperature (package surface temperature) : 215°C or below Time at temperature of 200°C or higher : 25 to 40 seconds Preheating time at 120 to 150°C : 30 to 60 seconds Maximum number of reflow processes : 3 times Maximum chlorine content of rosin flux (% mass) : 0.2%(Wt.) or below	VP215
Wave Soldering	Peak temperature (molten solder temperature) : 260°C or below Time at peak temperature : 10 seconds or less Preheating temperature (package surface temperature) : 120°C or below Maximum number of flow processes : 1 time Maximum chlorine content of rosin flux (% mass) : 0.2%(Wt.) or below	WS260
Partial Heating	Peak temperature (pin temperature) : 350°C or below Soldering time (per side of device) : 3 seconds or less Maximum chlorine content of rosin flux (% mass) : 0.2%(Wt.) or below	HS350

Caution Do not use different soldering methods together (except for partial heating).

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